

## General Description

The MY50N03D uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

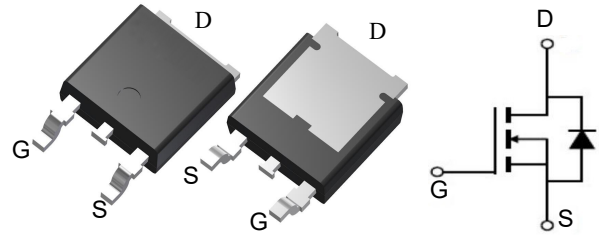


## Features

|                              |     |            |
|------------------------------|-----|------------|
| $V_{DSS}$                    | 30  | V          |
| $I_D$                        | 50  | A          |
| $R_{DS(ON)}(at V_{GS}=10V)$  | <9  | m $\Omega$ |
| $R_{DS(ON)}(at V_{GS}=4.5V)$ | <15 | m $\Omega$ |

## Application

- Battery protection
- Load switch
- Uninterruptible power supply



## Package Marking and Ordering Information

| Product ID | Pack      | Marking  | Qty(PCS) |
|------------|-----------|----------|----------|
| MY50N03D   | TO-252-2L | MY50N03D | 2500     |

## Absolute Maximum Ratings ( $T_c=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol                          | Parameter                                        | Rating     | Units                |
|---------------------------------|--------------------------------------------------|------------|----------------------|
| $V_{DS}$                        | Drain-Source Voltage                             | 30         | V                    |
| $V_{GS}$                        | Gate-Source Voltage                              | $\pm 20$   | V                    |
| $I_{D@T_C=25^{\circ}\text{C}}$  | Continuous Drain Current, $V_{GS} @ 10V^1$       | 50         | A                    |
| $I_{D@T_C=100^{\circ}\text{C}}$ | Continuous Drain Current, $V_{GS} @ 10V^1$       | 30         | A                    |
| $I_{D@T_A=25^{\circ}\text{C}}$  | Continuous Drain Current, $V_{GS} @ 10V^1$       | 11         | A                    |
| $I_{D@T_A=70^{\circ}\text{C}}$  | Continuous Drain Current, $V_{GS} @ 10V^1$       | 9          | A                    |
| $I_{DM}$                        | Pulsed Drain Current <sup>2</sup>                | 112        | A                    |
| EAS                             | Single Pulse Avalanche Energy <sup>3</sup>       | 24.2       | mJ                   |
| $I_{AS}$                        | Avalanche Current                                | 22         | A                    |
| $P_{D@T_C=25^{\circ}\text{C}}$  | Total Power Dissipation <sup>4</sup>             | 37.5       | W                    |
| $P_{D@T_A=25^{\circ}\text{C}}$  | Total Power Dissipation <sup>4</sup>             | 2.42       | W                    |
| $T_{STG}$                       | Storage Temperature Range                        | -55 to 175 | $^{\circ}\text{C}$   |
| $T_J$                           | Operating Junction Temperature Range             | -55 to 175 | $^{\circ}\text{C}$   |
| $R_{\theta JA}$                 | Thermal Resistance Junction-Ambient <sup>1</sup> | 62         | $^{\circ}\text{C/W}$ |
| $R_{\theta JC}$                 | Thermal Resistance Junction-Case <sup>1</sup>    | 4          | $^{\circ}\text{C/W}$ |

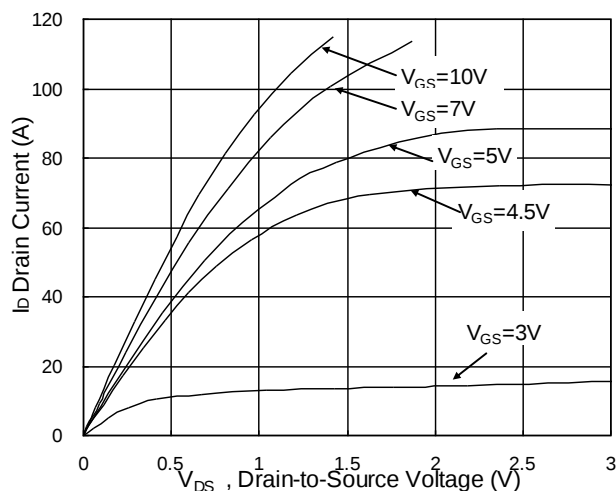
Electrical Characteristics ( $T_J=25^\circ\text{C}$ , unless otherwise noted)

| Symbol                       | Parameter                                      | Conditions                                              | Min. | Typ.   | Max.      | Unit                |
|------------------------------|------------------------------------------------|---------------------------------------------------------|------|--------|-----------|---------------------|
| $BV_{DSS}$                   | Drain-Source Breakdown Voltage                 | $V_{GS}=0V$ , $I_D=250\mu A$                            | 30   | ---    | ---       | V                   |
| $\Delta BV_{DSS}/\Delta T_J$ | BVDSS Temperature Coefficient                  | Reference to $25^\circ\text{C}$ , $I_D=1mA$             | ---  | 0.0193 | ---       | $V/^\circ\text{C}$  |
| $R_{DS(ON)}$                 | Static Drain-Source On-Resistance <sup>2</sup> | $V_{GS}=10V$ , $I_D=30A$                                | ---  | ---    | 9         | $m\Omega$           |
|                              |                                                | $V_{GS}=4.5V$ , $I_D=15A$                               | ---  | ---    | 15        |                     |
| $V_{GS(th)}$                 | Gate Threshold Voltage                         | $V_{GS}=V_{DS}$ , $I_D=250\mu A$                        | 1.2  | ---    | 2.5       | V                   |
| $\Delta V_{GS(th)}$          | $V_{GS(th)}$ Temperature Coefficient           |                                                         | ---  | -3.97  | ---       | $mV/^\circ\text{C}$ |
| $I_{DSS}$                    | Drain-Source Leakage Current                   | $V_{DS}=24V$ , $V_{GS}=0V$ , $T_J=25^\circ\text{C}$     | ---  | ---    | 1         | $\mu A$             |
|                              |                                                | $V_{DS}=24V$ , $V_{GS}=0V$ , $T_J=55^\circ\text{C}$     | ---  | ---    | 5         |                     |
| $I_{GSS}$                    | Gate-Source Leakage Current                    | $V_{GS}=\pm 20V$ , $V_{DS}=0V$                          | ---  | ---    | $\pm 100$ | nA                  |
| $g_{fs}$                     | Forward Transconductance                       | $V_{DS}=5V$ , $I_D=30A$                                 | ---  | 34     | ---       | S                   |
| $R_g$                        | Gate Resistance                                | $V_{DS}=0V$ , $V_{GS}=0V$ , $f=1MHz$                    | ---  | 1.8    | ---       | $\Omega$            |
| $Q_g$                        | Total Gate Charge (4.5V)                       | $V_{DS}=15V$ , $V_{GS}=4.5V$ , $I_D=15A$                | ---  | 9.8    | ---       | nC                  |
| $Q_{gs}$                     | Gate-Source Charge                             |                                                         | ---  | 4.2    | ---       |                     |
| $Q_{gd}$                     | Gate-Drain Charge                              |                                                         | ---  | 3.6    | ---       |                     |
| $T_{d(on)}$                  | Turn-On Delay Time                             | $V_{DD}=15V$ , $V_{GS}=10V$ ,<br>$R_G=3.3$<br>$I_D=15A$ | ---  | 4      | ---       | ns                  |
| $T_r$                        | Rise Time                                      |                                                         | ---  | 8      | ---       |                     |
| $T_{d(off)}$                 | Turn-Off Delay Time                            |                                                         | ---  | 31     | ---       |                     |
| $T_f$                        | Fall Time                                      |                                                         | ---  | 4      | ---       |                     |
| $C_{iss}$                    | Input Capacitance                              | $V_{DS}=15V$ , $V_{GS}=0V$ , $f=1MHz$                   | ---  | 940    | ---       | pF                  |
| $C_{oss}$                    | Output Capacitance                             |                                                         | ---  | 131    | ---       |                     |
| $C_{rss}$                    | Reverse Transfer Capacitance                   |                                                         | ---  | 109    | ---       |                     |
| $I_S$                        | Continuous Source Current <sup>1,5</sup>       | $V_G=V_D=0V$ , Force Current                            | ---  | ---    | 43        | A                   |
| $I_{SM}$                     | Pulsed Source Current <sup>2,5</sup>           |                                                         | ---  | ---    | 112       | A                   |
| $V_{SD}$                     | Diode Forward Voltage <sup>2</sup>             | $V_{GS}=0V$ , $I_S=1A$ , $T_J=25^\circ\text{C}$         | ---  | ---    | 1         | V                   |
| $t_{rr}$                     | Reverse Recovery Time                          | $I_F=30A$ , $dI/dt=100A/\mu s$ ,                        | ---  | 8.5    | ---       | nS                  |
| $Q_{rr}$                     | Reverse Recovery Charge                        | $T_J=25^\circ\text{C}$                                  | ---  | 2.2    | ---       | nC                  |

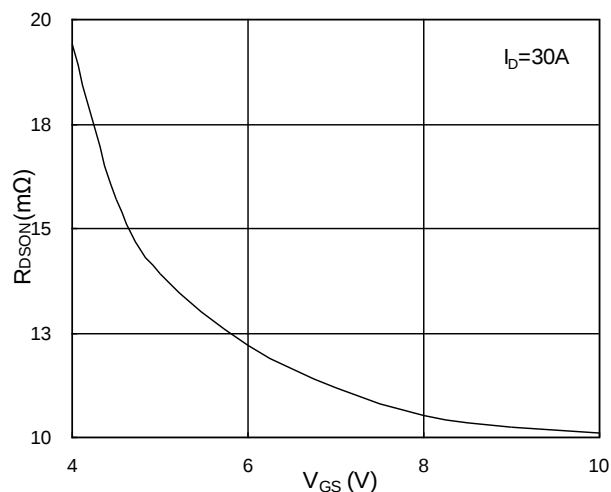
Note :

- 1 .The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 20Z copper.
- 2.The data tested by pulsed , pulse width  $\leq 300\mu s$  , duty cycle  $\leq 2\%$
- 3 .The EAS data shows Max. rating . The test condition is  $V_{DD}=25V$ ,  $V_{GS}=10V$ ,  $L=0.1mH$ ,  $I_{AS}=22A$
- 4.The power dissipation is limited by  $175^\circ\text{C}$  junction temperature
- 5.The data is theoretically the same as  $I_D$  and  $I_{DM}$  , in real applications , should be limited by total power dissipation.

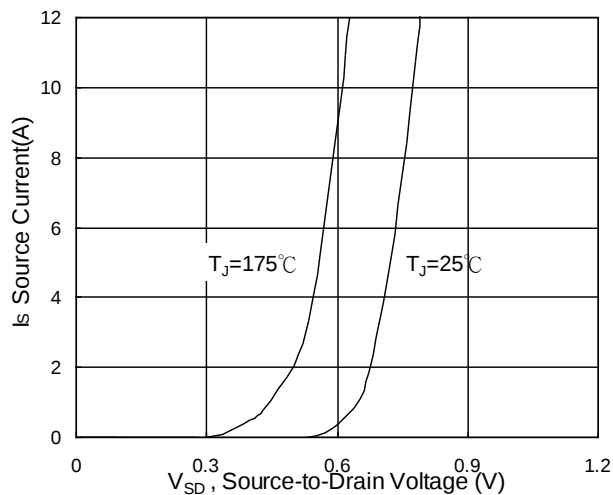
## Typical Characteristics



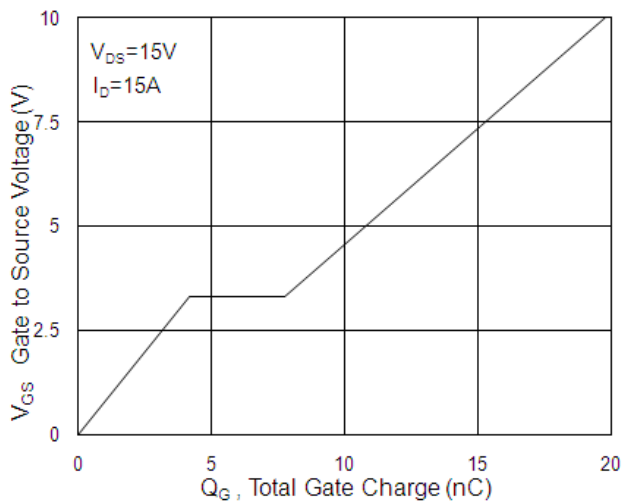
**Fig.1 Typical Output Characteristics**



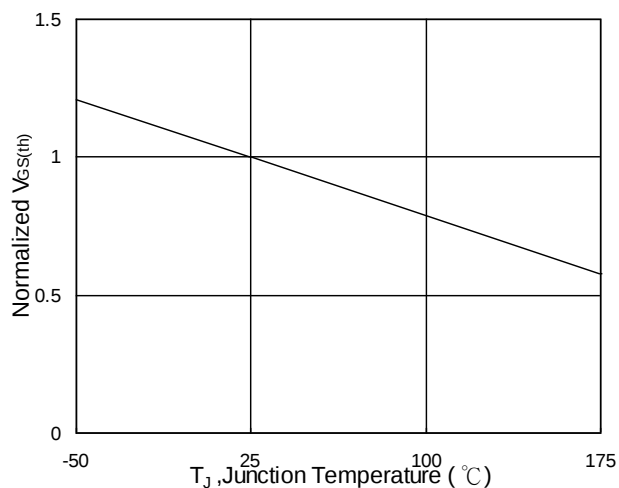
**Fig.2 On-Resistance vs. G-S Voltage**



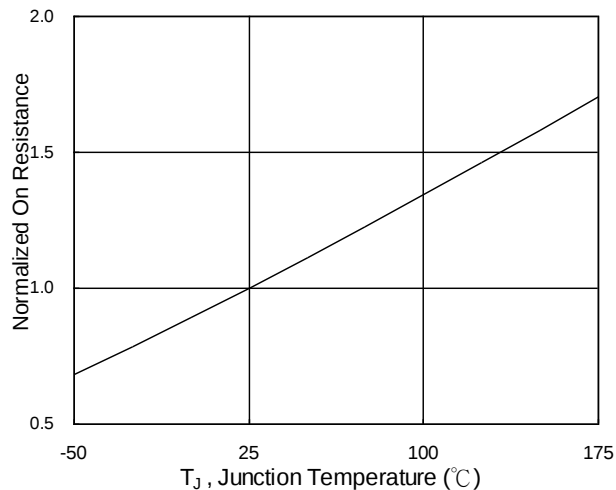
**Fig.3 Forward Characteristics of Reverse**



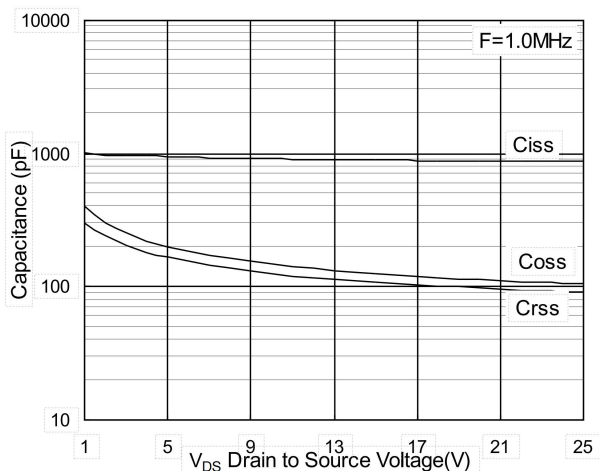
**Fig.4 Gate-Charge Characteristics**



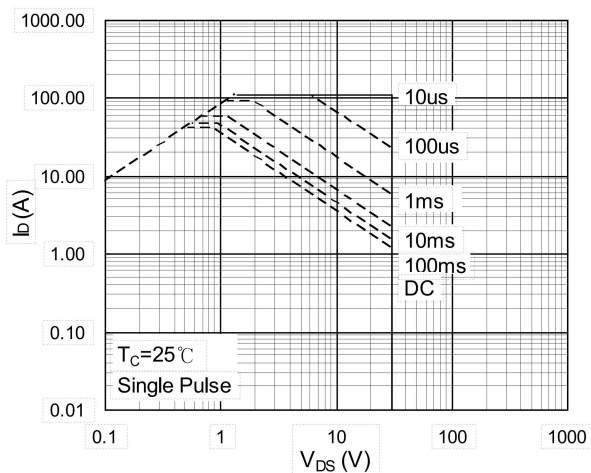
**Fig.5 Normalized  $V_{GS(th)}$  vs.  $T_J$**



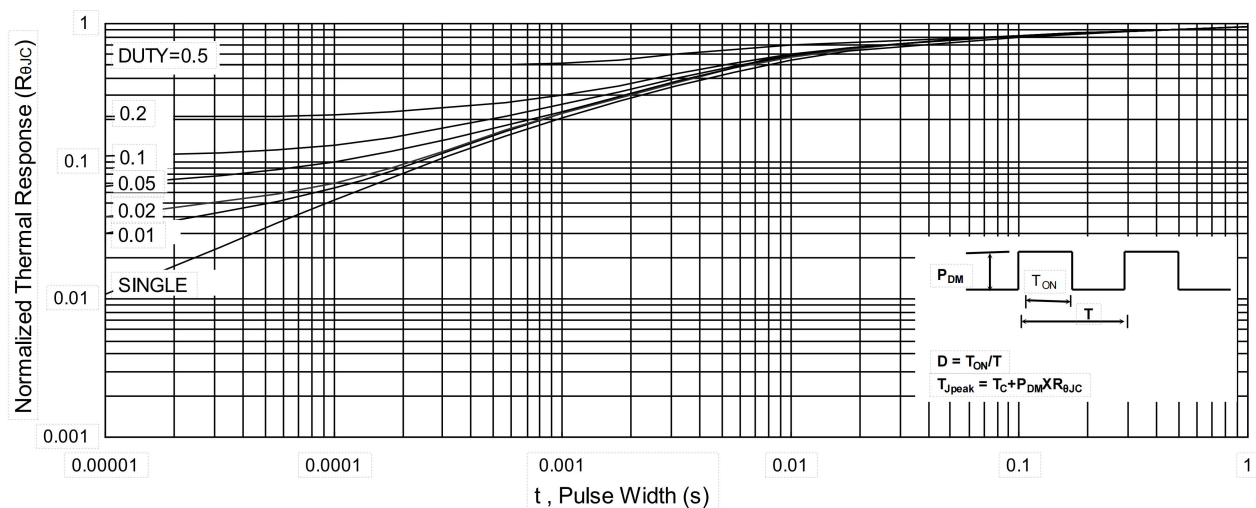
**Fig.6 Normalized  $R_{DS(on)}$  vs.  $T_J$**



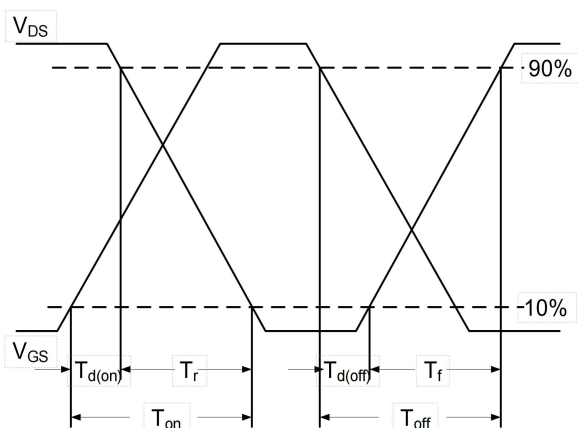
**Fig.7 Capacitance**



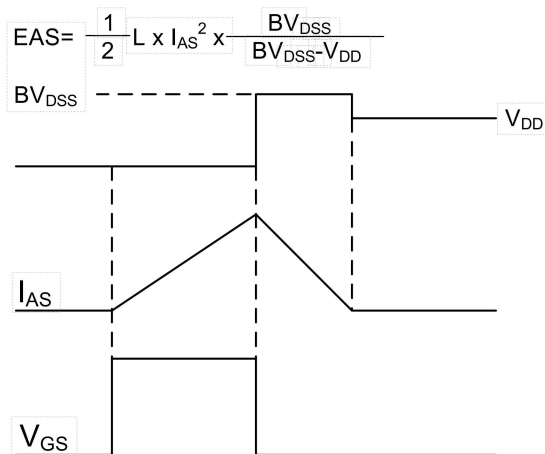
**Fig.8 Safe Operating Area**



**Fig.9 Normalized Maximum Transient Thermal Impedance**

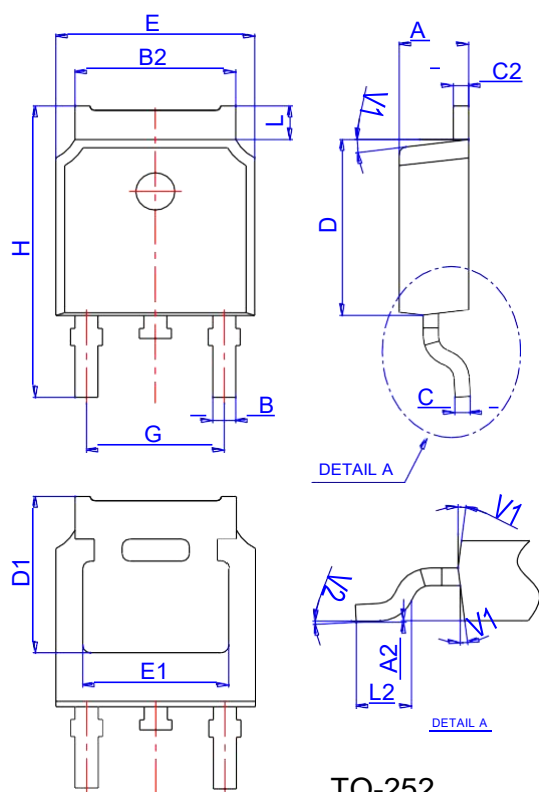


**Fig.10 Switching Time Waveform**



**Fig.11 Unclamped Inductive Switching Waveform**

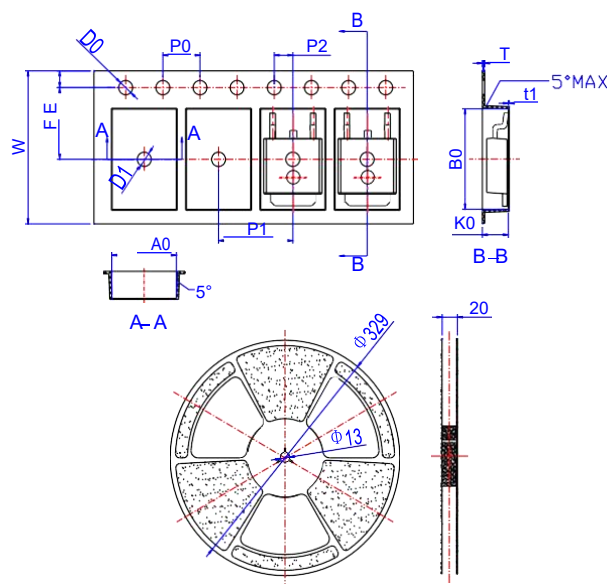
**Package Mechanical Data-TO-252-JQ Single**



TO-252

| Ref. | Dimensions  |      |       |          |      |       |
|------|-------------|------|-------|----------|------|-------|
|      | Millimeters |      |       | Inches   |      |       |
|      | Min.        | Typ. | Max.  | Min.     | Typ. | Max.  |
| A    | 2.10        |      | 2.50  | 0.083    |      | 0.098 |
| A2   | 0           |      | 0.10  | 0        |      | 0.004 |
| B    | 0.66        |      | 0.86  | 0.026    |      | 0.034 |
| B2   | 5.18        |      | 5.48  | 0.202    |      | 0.216 |
| C    | 0.40        |      | 0.60  | 0.016    |      | 0.024 |
| C2   | 0.44        |      | 0.58  | 0.017    |      | 0.023 |
| D    | 5.90        |      | 6.30  | 0.232    |      | 0.248 |
| D1   | 5.30REF     |      |       | 0.209REF |      |       |
| E    | 6.40        |      | 6.80  | 0.252    |      | 0.268 |
| E1   | 4.63        |      |       | 0.182    |      |       |
| G    | 4.47        |      | 4.67  | 0.176    |      | 0.184 |
| H    | 9.50        |      | 10.70 | 0.374    |      | 0.421 |
| L    | 1.09        |      | 1.21  | 0.043    |      | 0.048 |
| L2   | 1.35        |      | 1.65  | 0.053    |      | 0.065 |
| V1   |             | 7°   |       |          | 7°   |       |
| V2   | 0°          |      | 6°    | 0°       |      | 6°    |

**Reel Specification-TO-252**



| Ref. | Dimensions  |       |       |        |       |       |
|------|-------------|-------|-------|--------|-------|-------|
|      | Millimeters |       |       | Inches |       |       |
|      | Min.        | Typ.  | Max.  | Min.   | Typ.  | Max.  |
| W    | 15.90       | 16.00 | 16.10 | 0.626  | 0.630 | 0.634 |
| E    | 1.65        | 1.75  | 1.85  | 0.065  | 0.069 | 0.073 |
| F    | 7.40        | 7.50  | 7.60  | 0.291  | 0.295 | 0.299 |
| D0   | 1.40        | 1.50  | 1.60  | 0.055  | 0.059 | 0.063 |
| D1   | 1.40        | 1.50  | 1.60  | 0.055  | 0.059 | 0.063 |
| P0   | 3.90        | 4.00  | 4.10  | 0.154  | 0.157 | 0.161 |
| P1   | 7.90        | 8.00  | 8.10  | 0.311  | 0.315 | 0.319 |
| P2   | 1.90        | 2.00  | 2.10  | 0.075  | 0.079 | 0.083 |
| A0   | 6.85        | 6.90  | 7.00  | 0.270  | 0.271 | 0.276 |
| B0   | 10.45       | 10.50 | 10.60 | 0.411  | 0.413 | 0.417 |
| K0   | 2.68        | 2.78  | 2.88  | 0.105  | 0.109 | 0.113 |
| T    | 0.24        |       | 0.27  | 0.009  |       | 0.011 |
| t1   | 0.10        |       |       | 0.004  |       |       |
| 10P0 | 39.80       | 40.00 | 40.20 | 1.567  | 1.575 | 1.583 |